TECHNICAL DATA DATA SHEET 314, REV. A

SCHOTTKY RECTIFIER Ultra Low Reverse Leakage 200°C Operating Temperature

Applications:

• Switching Power Supply • Converters • Free-Wheeling Diodes • Polarity Protection Diode

Features:

- Ultra low Reverse Leakage Current
- Soft Reverse Recovery at Low and High Temperature
- Very Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability
- Guaranteed Reverse Avalanche Characteristics
- Out Performs 200 Volt Ultrafast Rectifiers

Maximum Ratings:

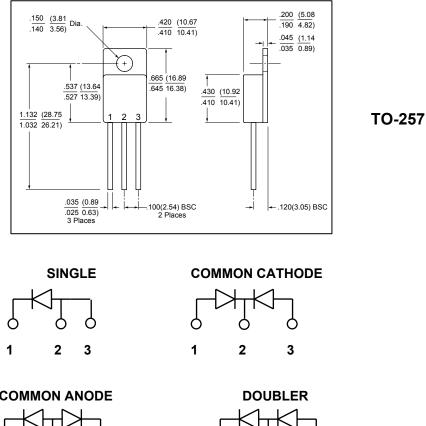
Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V _{RWM}	-	200	V
Max. Average Forward	I _{F(AV)}	50% duty cycle, rectangular	16	А
Current		wave form		
Max. Peak One Cycle Non-	I _{FSM}	8.3 ms, half Sine wave ⁽¹⁾	75	A
Repetitive Surge Current				
Max. Junction Temperature	TJ	-	-65 to +200	°C
Max. Storage Temperature	T _{stg}	-	-65 to +200	°C

Electrical Characteristics:

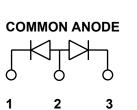
Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V_{F1}	@ 15A, Pulse, T _J = 25 °C	1.01	V
	V_{F2}	@ 15A, Pulse, T _J = 125 °C	0.85	V
Max. Reverse Current	I _{R1}	@V _R = 200V, Pulse,	0.05	μA
		T _J = 25 °C		
	I _{R2}	@V _R = 200V, Pulse,	1.0	mA
		T _J = 125 °C		
Max. Junction Capacitance	CT	@V _R = 5V, T _C = 25 °C	300	pF
		f _{SIG} = 1MHz,		
		V _{SIG} = 50mV (p-p)		
Max. Reverse Recovery Time	t _{rr}	I _F = 0.5A, I _R = 1.0A,	16	nsec
		I _{RM} = 0.25 A, T _J = 25°C		
Max. Thermal Resistance	$R_{ ext{ heta}JC}$	-	2.1	°C/W

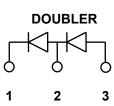
(1) in SHD package

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Mechanical Dimensions: In Inches / mm

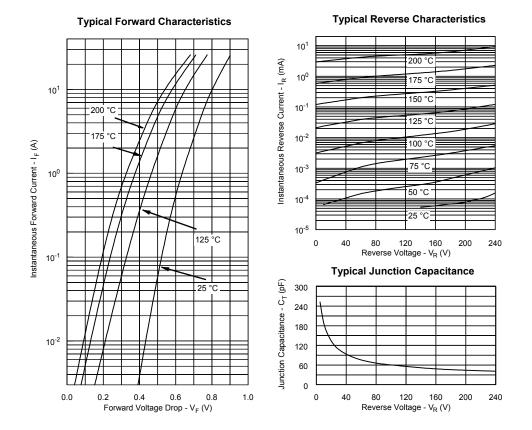




PINOUT TABLE

TYPE	PIN 1	PIN 2	PIN 3
SINGLE RECTIFIER	CATHODE	ANODE	ANODE
DUAL RECTIFIER, COMMON CATHODE (P)	ANODE 1	COMMON CATHODE	ANODE 2
DUAL RECTIFIER, COMMON ANODE (N)	CATHODE 1	COMMON ANODE	CATHODE 2
DUAL RECTIFIER, DOUBLER (D)	ANODE	ANODE/CATHODE	CATHODE

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Note: The V_f curves shown are for the SD125SCU200 unpackaged die only.

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